**會源"B**T139X"供应商

## **BT139X series**

#### **GENERAL DESCRIPTION**

Glass passivated triacs in a full pack, plastic envelope, intended for use in applications requiring high bidirectional transient and blocking voltage capability and high thermal cycling performance. Typical applications include motor control, industrial and domestic lighting, heating and static switching.

#### QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	MAX.	MAX.	UNIT
	BT139X- BT139X- BT139X- BT139X-	500 500F 500G	600 600F 600G	800 800F 800G	
V <sub>DRM</sub>	Repetitive peak off-state	500	600	800	V
I <sub>T(RMS)</sub> I <sub>TSM</sub>	voltages RMS on-state current Non-repetitive peak on-state current	16 140	16 140	16 140	A A

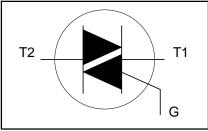
#### **PINNING - SOT186A**

PIN	DESCRIPTION
1	main terminal 1
2	main terminal 2
3	gate
case	isolated

#### PIN CONFIGURATION

# 

# SYMBOL



#### LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.		MAX.		UNIT
V <sub>drm</sub>	Repetitive peak off-state voltages		-	<b>-500</b> 500 <sup>1</sup>	<b>-600</b> 600 <sup>1</sup>	<b>-800</b> 800	V
I <sub>T(RMS)</sub> I <sub>TSM</sub>	RMS on-state current Non-repetitive peak on-state current	full sine wave; $T_{hs} \le 38$ °C full sine wave; $T_j = 25$ °C prior to surge	-		16		A
		t = 20  ms	-		140		A
124	1 <sup>2</sup> t for final a	t = 16.7  ms	-		150		A A <sup>2</sup> s
l²t dI <sub>⊤</sub> /dt	I <sup>2</sup> t for fusing Repetitive rate of rise of on-state current after	t = 10 ms $I_{TM} = 20 \text{ A}; I_G = 0.2 \text{ A};$ $dI_G/dt = 0.2 \text{ A}/\mu \text{s}$	-		98		A⁻s
	triggering	T2+G+	-		50		A/μs
		T2+ G-	-		50		A/μs
		T2- G- T2- G+	-		50		A/μs
1	Peak gate current	12- G+	-		10		A/μs Å
I <sub>GM</sub> V <sub>GM</sub>	Peak gate voltage				25		V V
P <sub>GM</sub>	Peak gate power		-		5 5		Ŵ
$\begin{array}{c} P_{G(AV)}\\ T_{stg}\\ T_{j} \end{array}$	Average gate power Storage temperature	over any 20 ms period	- -40		0.5 150		°℃ ℃
Ij	Operating junction temperature		-		125		

<sup>1</sup> Although not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 15  $A/\mu s$ .

## **ISOLATION LIMITING VALUE & CHARACTERISTIC**

 $T_{hs} = 25$  °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>isol</sub>	R.M.S. isolation voltage from all three terminals to external heatsink	f = 50-60 Hz; sinusoidal waveform; R.H. ≤ 65% ; clean and dustfree	-		2500	V
C <sub>isol</sub>	Capacitance from T2 to external heatsink	f = 1 MHz	-	10	-	pF

#### THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R <sub>th j-hs</sub> R <sub>th j-a</sub>	Thermal resistance junction to heatsink Thermal resistance junction to ambient	full or half cycle with heatsink compound without heatsink compound in free air		- - 55	4.0 5.5 -	K/W K/W K/W

#### STATIC CHARACTERISTICS

 $T_j = 25$  °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.		MAX.		UNIT
I <sub>GT</sub>	Gate trigger current	<b>BT139X-</b> V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A				F	G	
G		T2+G+ T2+G-	-	5 8	35 35	25 25	50 50	mA mA
		T2- G- T2- G+	-	10 22	35 70	25 70	50 100	mA mA
IL.	Latching current	$V_{D} = 12 \text{ V}; \text{ I}_{GT} = 0.1 \text{ A}$ T2+ G+ T2+ G-	-	7 20	40 60	40 60	60 90	mA mA
I <sub>H</sub>	Holding current	T2- G- T2- G+ V <sub>D</sub> = 12 V; I <sub>GT</sub> = 0.1 A	- -	8 10 6	40 60 30	40 60 30	60 90 60	mA mA mA
V <sub>T</sub> V <sub>GT</sub>	On-state voltage Gate trigger voltage	$I_{T} = 20 \text{ A}$ $V_{D} = 12 \text{ V}; I_{T} = 0.1 \text{ A}$ $V_{D} = 400 \text{ V}; I_{T} = 0.1 \text{ A};$	- - 0.25	1.2 0.7 0.4		1.6 1.5 -	•	
I <sub>D</sub>	Off-state leakage current		-	0.1		0.5		mA

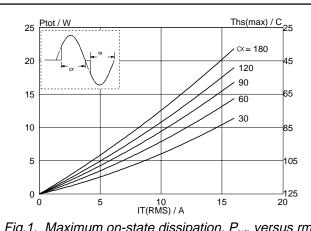
## **DYNAMIC CHARACTERISTICS**

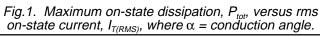
 $T_j = 25$  °C unless otherwise stated

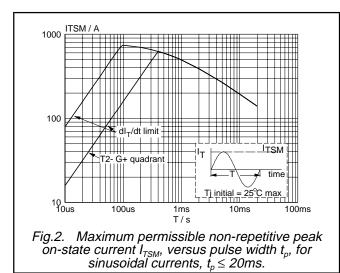
SYMBOL	PARAMETER	CONDITIONS		MIN.		TYP.	MAX.	UNIT
dV <sub>D</sub> /dt	Critical rate of rise of off-state voltage	BT139X- $V_{DM} = 67\% V_{DRM(max)};$ $T_i = 125 °C; exponential$	 100	<b>F</b> 50	<b>G</b> 200	250	-	V/µs
dV <sub>com</sub> ∕dt	Critical rate of change of commutating voltage	waveform; gate open circuit $V_{DM} = 400 \text{ V}; \text{ T}_{j} = 95 ^{\circ}\text{C};$ $I_{T(RMS)} = 16 \text{ A};$ $dI_{com}/dt = 7.2 \text{ A/ms}; \text{ gate}$	-	-	10	20	-	V/µs
t <sub>gt</sub>	Gate controlled turn-on time	open circuit $I_{TM} = 20 \text{ A}; V_D = V_{DRM(max)};$ $I_G = 0.1 \text{ A}; dI_G/dt = 5 \text{ A/}\mu\text{s}$	-	-	-	2	-	μs

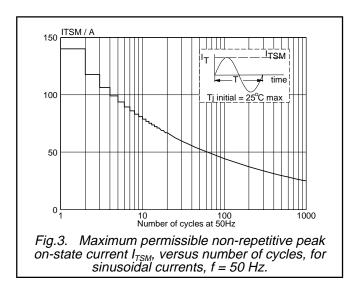
# T耷視"BT139X"供应商

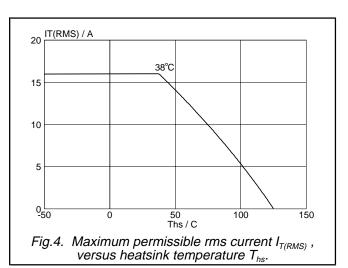
# BT139X series











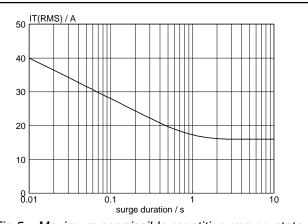
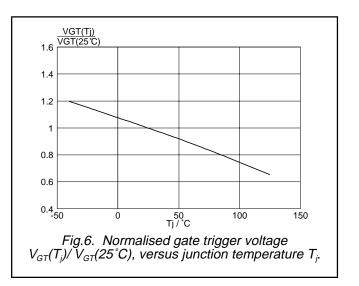
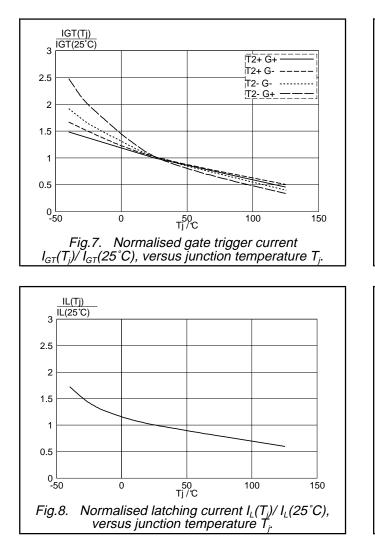
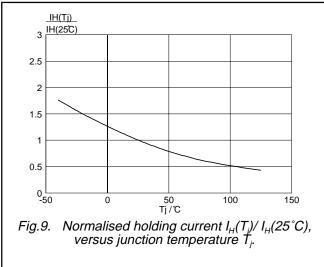
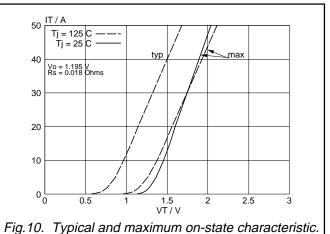


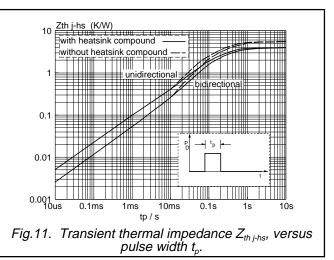
Fig.5. Maximum permissible repetitive rms on-state current  $I_{T(RMS)}$ , versus surge duration, for sinusoidal currents, f = 50 Hz;  $T_{hs} \leq 38$  °C.

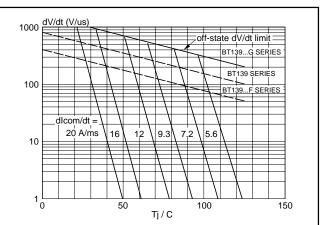


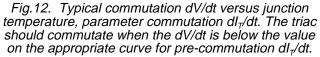




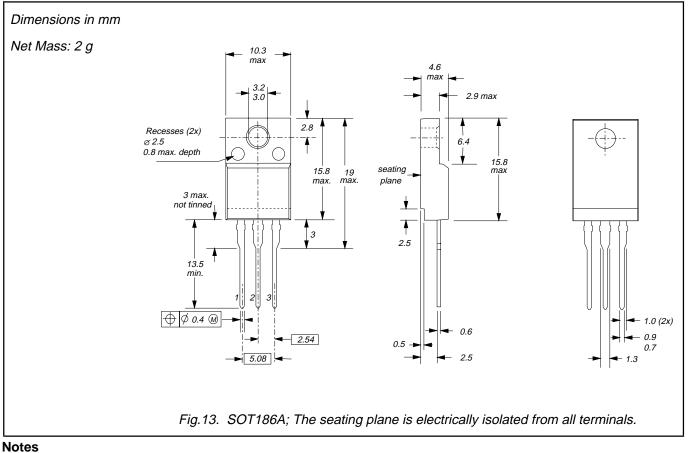








### **MECHANICAL DATA**



Refer to mounting instructions for F-pack envelopes.
Epoxy meets UL94 V0 at 1/8".

#### DEFINITIONS

Data sheet status					
Objective specification	This data sheet contains target or goal specifications for product development.				
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.				
Product specification	This data sheet contains final product specifications.				
Limiting values					
or more of the limiting val operation of the device at	in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one lues may cause permanent damage to the device. These are stress ratings only and t these or at any other conditions above those given in the Characteristics sections of applied. Exposure to limiting values for extended periods may affect device reliability.				
Application information					
Where application inform	ation is given, it is advisory and does not form part of the specification.				
© Philips Electronics N	.V. 1997				
All rights are reserved R	Reproduction in whole or in part is prohibited without the prior written consent of the				

All rights are reserved. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner.

The information presented in this document does not form part of any quotation or contract, it is believed to be accurate and reliable and may be changed without notice. No liability will be accepted by the publisher for any consequence of its use. Publication thereof does not convey nor imply any license under patent or other industrial or intellectual property rights.

#### LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.